

INFORMATION DISCLOSURE CITATION (USE SEVERAL SHEETS IF NECESSARY)				Complete if Known		
				Application Number	10/553,573	
Sheet		1	of	1	Filing Date	October 17, 2005
					First Named Inventor	Christian DUSSARRAT
					Art Unit	1715
					Examiner Name	Elizabeth A. Burkhart
					Attorney Docket Number	Serie 6070
U.S. PATENT DOCUMENTS						
Examiner Initials	Cite No.	Document Number	Publication Date	Name	Pages Column, Lines Where Relevant Passages or Relevant Figures Appear	
	A1	US 5 932 286	8/03/1999	BEINGLASS et al.		
FOREIGN PATENT DOCUMENTS						
Examiner Initials	Cite No.	Document Number	Publication Date	Name	Pages Column, Lines Where Relevant Passages or Relevant Figures Appear	T
NON PATENT LITERATURE DOCUMENTS						
Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published				T
	C1	PEREIRA, M.A. et al., "Silicon nitride deposited by ECR-CVD at room temperature for LOCOS isolation technology," Applied Surface Science 212-213 (2003), pp. 388-392				
	C2	YOTA, J. et al., "A comparative study on inductively-coupled plasma high-density plasma, plasma-enhanced, and low pressure chemical vapor deposition silicon nitride films," J. Vac. Sci. Technol. A 18(2), Mar/Apr 2000, pp. 372-376				
Examiner			Date Considered			
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